

KSC2734

MIXER, OSC. FOR UHF TV TUNER

• High Current Gain Bandwidth Product : f_T =3.5GHz (TYP.)



1. Base 2. Emitter 3. Collector

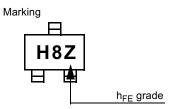
NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	20	V
V _{CEO}	Collector-Emitter Voltage	12	V
V _{EBO}	Emitter-Base Voltage	3	V
I _C	Collector Current	50	mA
P _C	Collector Dissipation	150	mW
TJ	Junction Temperature	125	°C
T _{STG}	Storage Temperature	-55 ~ 125	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μA, I _E =0	20			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =1mA, I _B =0	12			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	3			V
I _{CBO}	Collector Cut-off Current	V _{CB} =15V, I _E =0			700	nA
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =5mA	20	90	200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =5mA			0.7	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =10mA	1.4	3.5		GHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		0.9	1.5	pF



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Typical Characteristics

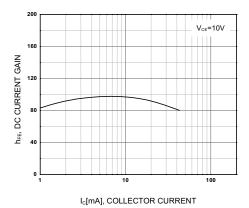


Figure 1. DC current Gain

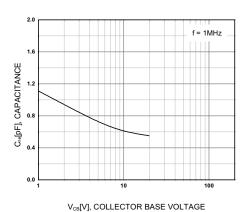


Figure 3. Collector Output Capacitance

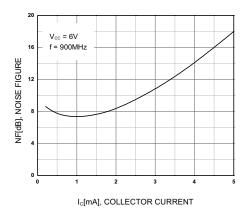


Figure 5. Noise Figure

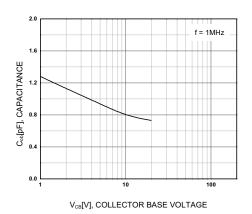


Figure 2. Reverse Transfer Capacitance

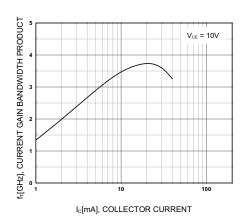


Figure 4. Current Gain Bandwidth Product

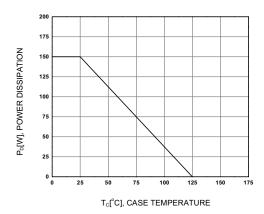


Figure 6. Power Derating

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Typical Characteristics (Continued)

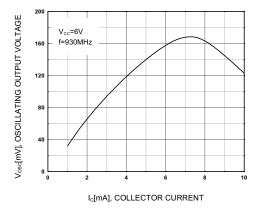


Figure 7. Oscillating Output Voltage vs. Collector Current

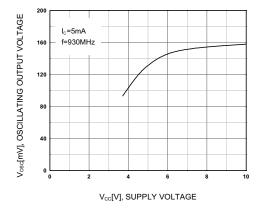


Figure 8. Oscillating Output Voltage vs. Supply Voltage

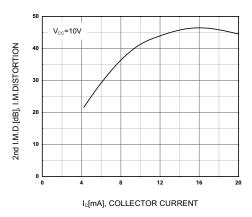


Figure 9. 2nd I.M. Distortion vs. Collector Current

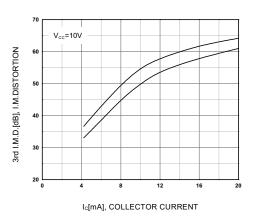


Figure 10. 3nd I.M. Distortion vs. Collector Current

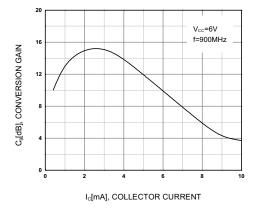


Figure 11. Conversion Gain vs. Collector Current

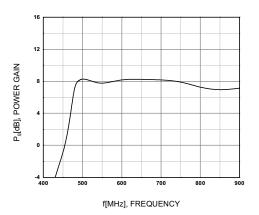
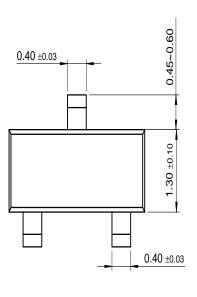


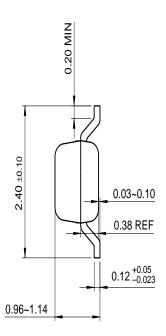
Figure 12. Power Gain vs. Frequency

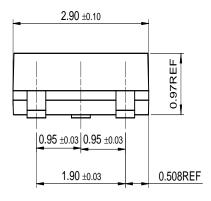
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Package Demensions

SOT-23







Dimensions in Millimeters

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